



JIANGSU CHANGJING ELECTRONICS TECHNOLOGY CO., LTD

TO-92L Plastic-Encapsulate Transistors

2SC2236 TRANSISTOR (NPN)**FEATURE**

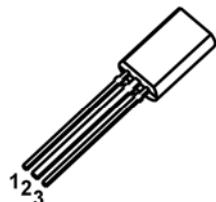
Complementary to 2SA966 and 3 Watts Output Applications.

TO-92L

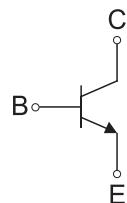
1. Emitter

2. Collector

3. Base

**MARKING**

C2236=Device code
Solid dot= Green molding compound device,
if none, the normal device
XXX=Code

Equivalent Circuit**ORDERING INFORMATION**

Part Number	Package	Packing Method	Pack Quantity
2SC2236	TO-92L	Bulk	500pcs/Bag
2SC2236-TA	TO-92L	Tape	2000pcs/Box

MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	30	V
V _{CEO}	Collector-Emitter Voltage	30	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current -Continuous	1.5	A
P _C	Collector Power Dissipation	0.9	W
T _J , T _{stg}	Operation Junction and Storage Temperature Range	-55~+150	°C

ELECTRICAL CHARACTERISTICS

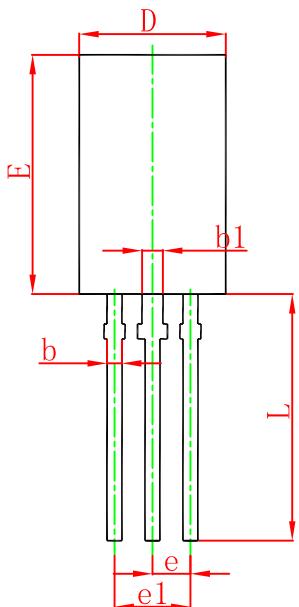
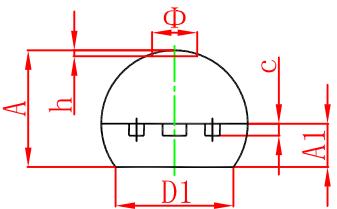
$T_a=25^\circ C$ unless otherwise specified

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V(BR)_{CBO}$	$I_C= 1mA, I_E=0$	30			V
Collector-emitter breakdown voltage	$V(BR)_{CEO}$	$I_C= 10mA, I_B=0$	30			V
Emitter-base breakdown voltage	$V(BR)_{EBO}$	$I_E= 1mA, I_C=0$	5			V
Collector cut-off current	I_{CBO}	$V_{CB}=30V, I_E=0$			0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=5V, I_C=0$			0.1	μA
DC current gain	h_{FE}	$V_{CE}=2 V, I_C= 500mA$	100		320	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C= 1.5 A, I_B= 0.03A$			2	V
Base-emitter voltage	V_{BE}	$I_C= 500 mA, V_{CE}= 2V$			1	V
Transition frequency	f_T	$V_{CE}= 2V, I_C= 500mA$		120		MHz
Collector output Capacitance	C_{ob}	$V_{CB}= 10V, I_E= 0, f=1MHz$			30	pF

CLASSIFICATION OF h_{FE}

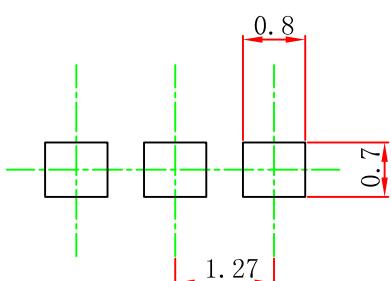
Rank	O	Y
Range	100-200	160-320

TO-92L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	3.750	4.050	0.148	0.159
A1	1.280	1.580	0.050	0.062
b	0.380	0.550	0.015	0.022
b1	0.620	0.780	0.024	0.031
c	0.350	0.450	0.014	0.018
D	4.750	5.050	0.187	0.199
D1	4.000		0.157	
E	7.850	8.150	0.309	0.321
e	1.270 TYP.		0.050 TYP.	
e1	2.440	2.640	0.096	0.104
L	13.800	14.200	0.543	0.559
Φ	1.600		0.063	
h	0.000	0.300	0.000	0.012

TO-92L Suggested Pad Layout



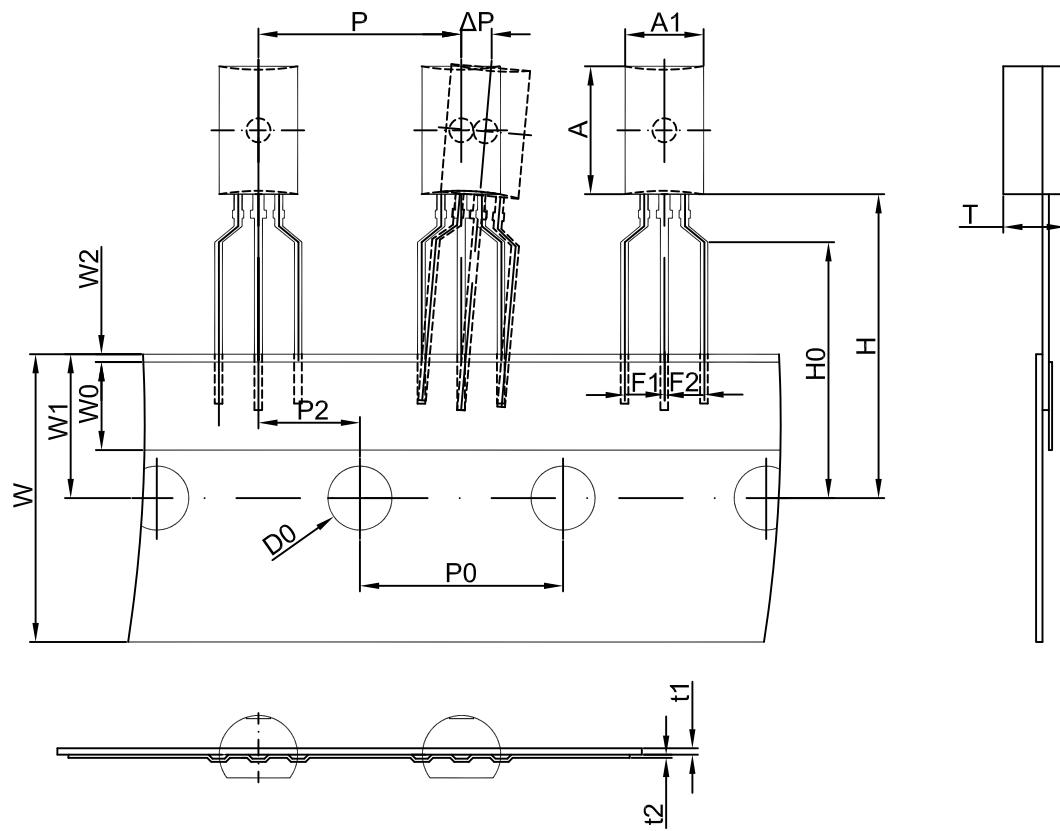
Note:

1. Controlling dimension: in millimeters.
2. General tolerance: ± 0.05 mm.
3. The pad layout is for reference purposes only.

NOTICE

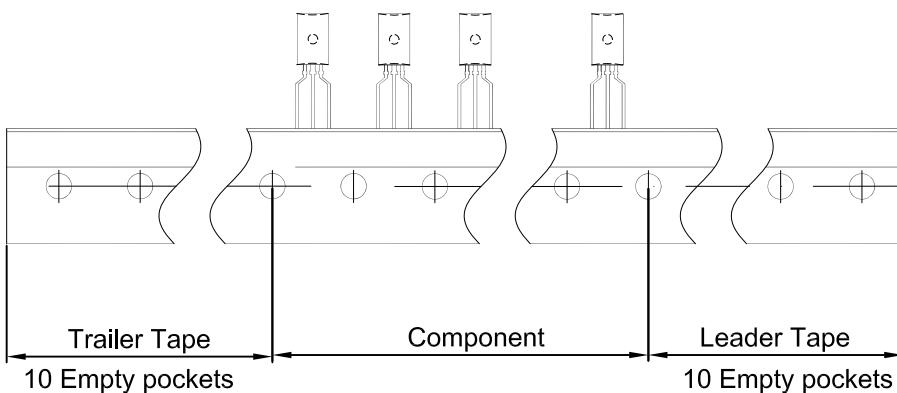
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TO-92L PACKAGE TAPING DIMENSION



Dimensions are in millimeter

A1	A	T	P	P0	P2	F1	F2	W
4.9	8.0	3.9	12.7	12.7	6.35	2.5	2.5	18.0
W0	W1	W2	H	H0	D0	t1	t2	ΔP
6.0	9.0	1.0	19.0	16.0	4.0	0.4	0.2	0



Package	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92L	2000 pcs	333×203×42	20,000 pcs	493×400×264

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